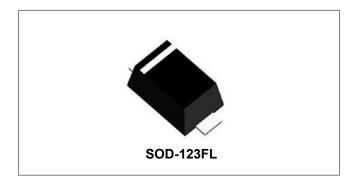






# S3D03065T 3A 650V SIC POWER SCHOTTKY RECTIFIERS



#### **Features**

- 175°C T<sub>J</sub> operation
- Ultra-low switching loss
- Switching speeds independent of operating temperature
- Low total conduction losses
- · High forward surge current capability
- High package isolation voltage
- Terminals finish: 100% Pure Tin
- "-A" is an AEC-Q101 qualified device
- Pb Free Device
- All SMC parts are traceable to the wafer lot
- Additional electrical and life testing can be performed upon request

### **Circuit Diagram**



#### **Description**

This 650V 3A diode is high voltage Schottky rectifier that has very low total conduction losses and very stable switching characteristics over temperature extremes. The S3D03065T is ideal for energy sensitive, high frequency applications in challenging environments.

#### **Applications**

- Alternative energy inverters
- Power Factor Correction (PFC)
- Free-Wheeling diodes
- Switching supply output rectification
- Reverse polarity protection







#### Maximum Ratings@T<sub>A</sub>=25°C unless otherwise specified

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V <sub>RRM</sub> V <sub>RWM</sub> V <sub>DC</sub>	-	650	V
	I <sub>F (AV)1</sub>	Tc=25°C	6	Α
Average Rectified Forward Current	I <sub>F (AV)2</sub>	Tc=100°C	4	Α
	I <sub>F (AV)3</sub>	Tc=125°C	3	Α
	I <sub>FRM1</sub>	10ms, Half Sine pulse, Tc=25°C	6	Α
Repetitive Peak Forward Surge Current	I <sub>FRM2</sub>	10ms, Half Sine pulse, Tc=110°C	4	Α
	I <sub>FSM1</sub>	10ms, Half Sine pulse, Tc=25°C	12	Α
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM2</sub>	10ms, Half Sine pulse, Tc=110°C	9	Α
	P <sub>tot1</sub>	Tc=25°C	15	W
Power Dissipation	P <sub>tot2</sub>	Tc=110℃	6.5	W

## Electrical Characteristics@T<sub>A</sub>=25°C unless otherwise specified

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	$V_{F1}$	@ 3A, Pulse, T <sub>J</sub> = 25 °C	1.4	1.7	V
	$V_{F2}$	@ 3A, Pulse, T <sub>J</sub> = 175 °C	1.6	2.0	V
Reverse Current*	I <sub>R1</sub>	$@V_R = \text{rated } V_R$ $T_J = 25  ^{\circ}\text{C}$	0.03	2	uA
	I <sub>R2</sub>	$@V_R = \text{rated } V_R$ $T_J = 175 ^{\circ}\text{C}$	0.3	20	uA
Junction Capacitance	Ст	V <sub>R</sub> =0V, T <sub>J</sub> =25℃, f=1MHz	230	-	pF
Reverse Recovery Charge	Qc	I <sub>F</sub> = 3A, di/dt = 200A/μs VR = 400 V, T <sub>J</sub> =25°C	14.35	-	nC
Capacitance Stored Energy	Ec	VR = 400 V, T <sub>J</sub> =25°C	3.51	-	μJ

<sup>\*</sup> Pulse width < 300  $\mu$ s, duty cycle < 2%



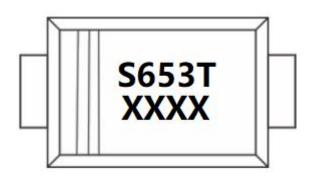




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	\$3D03065T	Units
Junction Temperature	TJ	-55 to +175	°C
Storage Temperature	T <sub>stg</sub>	-55 to +175	°C
Typical Thermal Resistance Junction to Case	R <sub>qJC</sub>	10	°C/W

### **Marking Diagram**



Where XXXX is YYWWL

= Device Type = Reverse Voltage (650V) 65 = Forward Current (3A) 3 T

= Package type = Year WW = Week = Lot Number

Cautions: Molding resin

Epoxy resin UL:94V-0

#### **Ordering Information**

Device	Package	Shipping
S3D03065T	SOD-123FL	3000pcs / reel

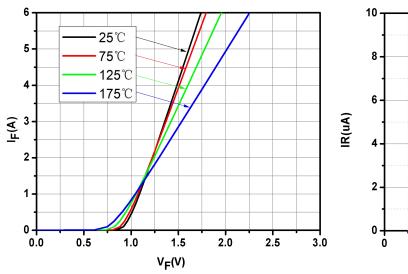
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.







### **Ratings and Characteristics Curves**



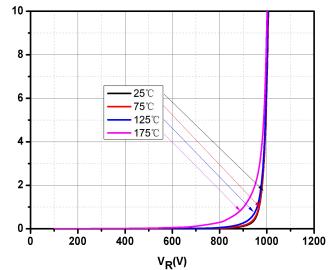
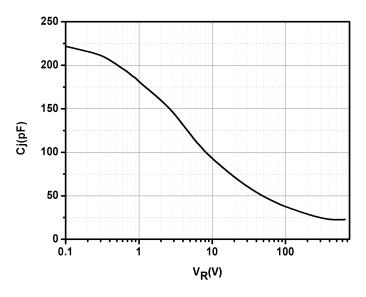
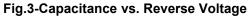


Fig.1-Typical Forward Voltage Characteristics

Fig.2-Typical Reverse Characteristics





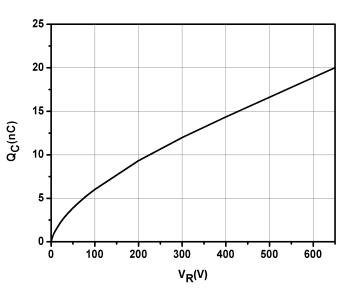


Fig.4-Total Capacitance Charge vs. Reverse Voltage

<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •







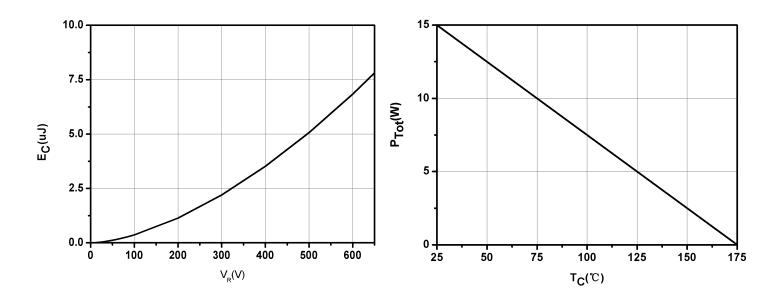


Fig.5-Capacitance Stored Energy

Fig.6-Power Derating

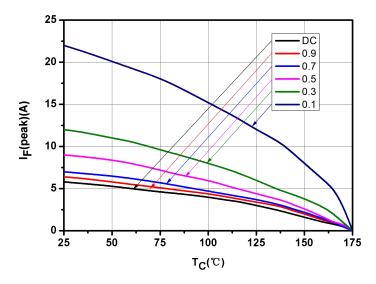


Fig.7-Current Derating

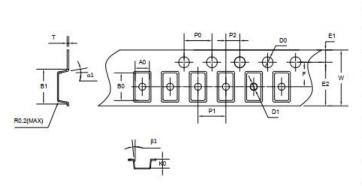
<sup>•</sup> http://www.smc-diodes.com - sales@ smc-diodes.com •





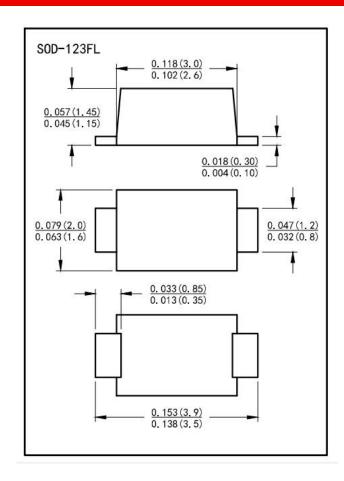


## **Carrier Tape & Reel Specification SOD-123FL**



项目	规格(mm)	允差(mm)	项目	规格(mm)	允差(mm)
W	8.00	+0.30/-0.10	A0	2.05	±0.10
E1	1.75	±0.10	В0	3.95	±0.10
F	3.50	±0.05	K0	1.45	±0.10
D0	1.50	+0.1/-0.0	T	0.23	±0.02
D1	1.00	+0.25/-0.0	10*P0	40.00	±0.20
P0	4.00	±0.10	α1	4°max	
P1	4.00	±0.10	β1	8°max	
P2	2.00	±0.05	B1 <sub>max</sub>	4.35	
			E2min	6.25	

#### **Mechanical Dimensions SOD-123FL**



- China Germany Korea Singapore United States
  - http://www.smc-diodes.com sales@ smc-diodes.com •







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